

Inventors' Name Search

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Search Results - Record(s) 1 through 4 of 4 returned.

1. Document ID: US 20050048778 A1

Using default format because multiple data bases are involved.

L7: Entry 1 of 4

File: PGPB

Mar 3, 2005

PGPUB-DOCUMENT-NUMBER: 20050048778

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20050048778 A1

TITLE: Use of thin SOI to inhibit relaxation of SiGe layers

PUBLICATION-DATE: March 3, 2005

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
<u>Bedell, Stephen W.</u>	Wappingers Falls	NY	US	
<u>Chen, Huajie</u>	Wappingers Falls	NY	US	
<u>Fogel, Keith E.</u>	Mohegan Lake	NY	US	
Sadana, Devendra K.	Pleasantville	NY	US	

US-CL-CURRENT: 438/689; 117/4

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	RWC	Drawn D
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2. Document ID: US 20050003229 A1

L7: Entry 2 of 4

File: PGPB

Jan 6, 2005

PGPUB-DOCUMENT-NUMBER: 20050003229

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20050003229 A1

TITLE: Defect reduction by oxidation of silicon

PUBLICATION-DATE: January 6, 2005

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
<u>Bedell, Stephen W.</u>	Wappingers Falls	NY	US	
<u>Chen, Huajie</u>	Wappingers Falls	NY	US	
Domenicucci, Anthony G.	New Paltz	NY	US	
<u>Fogel, Keith E.</u>	Mohegan Lake	NY	US	

Sadana, Devendra K.

Pleasantville

NY

US

US-CL-CURRENT: 428/641; 438/514

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KMPC	Drawn D
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3. Document ID: US 20040259334 A1

L7: Entry 3 of 4

File: PGPB

Dec 23, 2004

PGPUB-DOCUMENT-NUMBER: 20040259334

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20040259334 A1

TITLE: High-quality SGOI by annealing near the alloy melting point

PUBLICATION-DATE: December 23, 2004

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
<u>Bedell, Stephen W.</u>	Wappingers Falls	NY	US	
<u>Chen, Huajie</u>	New Paltz	NY	US	
Domenicucci, Anthony G.	Mohegan Lake	NY	US	
<u>Fogel, Keith E.</u>	Clinton Corners	NY	US	
Murphy, Richard J.	Pleasantville	NY	US	
Sadana, Devendra K.			US	

US-CL-CURRENT: 438/478

Full	Title	Citation	Front	Review	Classification	Date	Reference	Sequences	Attachments	Claims	KMPC	Drawn D
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4. Document ID: US 20040242006 A1

L7: Entry 4 of 4

File: PGPB

Dec 2, 2004

PGPUB-DOCUMENT-NUMBER: 20040242006

PGPUB-FILING-TYPE: new

DOCUMENT-IDENTIFIER: US 20040242006 A1

TITLE: SiGe lattice engineering using a combination of oxidation, thinning and epitaxial regrowth

PUBLICATION-DATE: December 2, 2004

INVENTOR-INFORMATION:

NAME	CITY	STATE	COUNTRY	RULE-47
<u>Bedell, Stephen W.</u>	Wappingers Falls	NY	US	
<u>Chen, Huajie</u>	Wappingers Falls	NY	US	
<u>Fogel, Keith E.</u>	Mohegan lake	NY	US	
Sadana, Devendra K.	Pleasantville	NY	US	

US-CL-CURRENT: 438/692[Full](#) | [Title](#) | [Citation](#) | [Front](#) | [Review](#) | [Classification](#) | [Date](#) | [Reference](#) | [Sequences](#) | [Attachments](#) | [Claims](#) | [KINIC](#) | [Drawn D](#)[Clear](#) | [Generate Collection](#) | [Print](#) | [Fwd Refs](#) | [Bkwd Refs](#) | [Generate OACS](#)

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